MICREL
The Infinite Bandwidth Company™

2.5/3.3V 1:22 HIGH-PERFORMANCE, LOW-VOLTAGE PECL BUS CLOCK DRIVER & TRANSLATOR w/ INTERNAL TERMINATION

ClockWorks™
SY89825U
**FINAL**

FEATURES

- **LVPECL or LVDS input to 22 LVPECL outputs**
- **100K ECL compatible outputs**
- **LVDS input includes 100Ω termination**
- **Guaranteed AC parameters over voltage:**
  - **> 2GHz f_{MAX} (toggle)**
  - **< 35ps max. ch-ch skew**
- **Low voltage operation: 2.5V, 3.3V**
- **Temperature range: –40°C to +85°C**
- **Output enable pin**
- **Available in a 64-Pin EPAD-TQFP**

DESCRIPTION

The SY89825U is a High Performance Bus Clock Driver with 22 differential LVPECL output pairs. This part is designed for use in low voltage (2.5V, 3.3V) applications which require a large number of outputs to drive precisely aligned, ultra low skew signals to their destination. The input is multiplexed from either LVDS or LVPECL by the CLK_SEL pin. The LVDS input includes a 100Ω internal termination, thus eliminating the need for external termination. The Output Enable (OE) is synchronous so that the outputs will only be enabled/disabled when they are already in the LOW state. This eliminates any chance of generating a runt clock pulse when the device is enabled/disabled as can happen with an asynchronous control.

The SY89825U features low pin-to-pin skew (35ps max.) —performance previously unachievable in a standard product having such a high number of outputs. The SY89825U is available in a single space saving package which provides a lower overall cost solution. In addition, a single chip solution improves timing budgets by eliminating the multiple device solution with their corresponding large part-to-part skew.

PIN CONFIGURATION

64-Pin EPAD-TQFP (Top View)
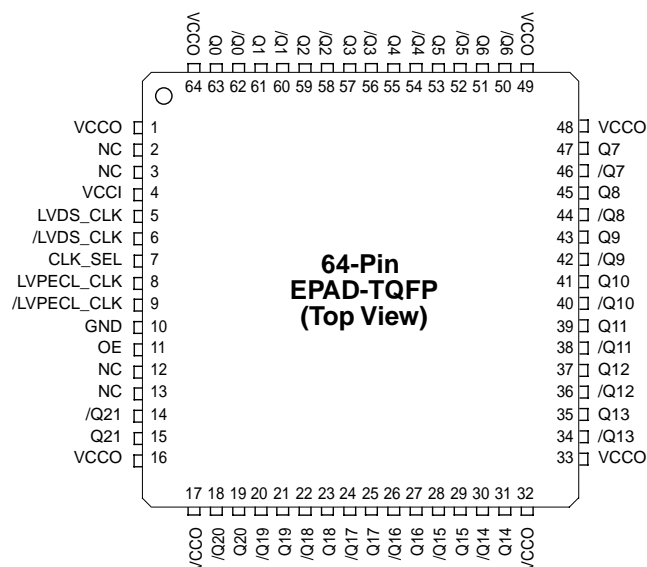
APPLICATIONS

- **High-performance PCs**
- **Workstations**
- **Parallel processor-based systems**
- **Other high-performance computing**
- **Communications**

PIN NAMES

Pin	Function
LVDS_CLK, /LVDS_CLK	Differential LVDS Inputs (Internal 100Ω termination included)
LVPECL_CLK, /LVPECL_CLK	Differential LVPECL Inputs.
CLK_SEL	Input CLK Select (LVTTL)
OE	Output Enable (LVTTL)
$Q_0 - Q_{21}$, $/Q_0 - /Q_{21}$	Differential LVPECL Outputs. Terminate with 50Ω to V_{CC}-2V
GND	Ground
V_{CCI}	Power Supply. Connect to V_{CC} on PCB. V_{CCI} and V_{CCO} are not internally connected
V_{CCO}	Power Supply for Output Buffer. Connect to V_{CCI} on PCB. V_{CCI} and V_{CCO} are not internally connected

LOGIC SYMBOL
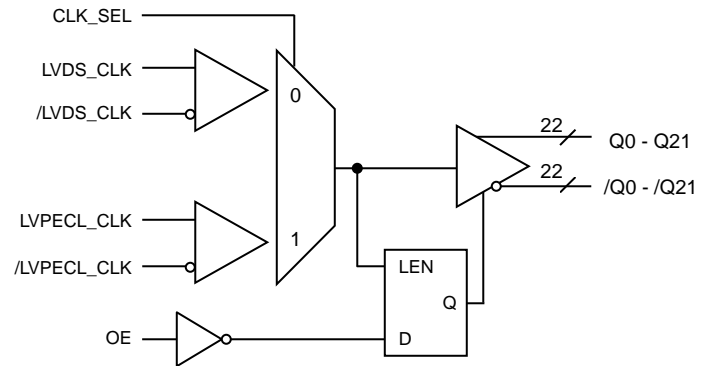
TRUTH TABLE

OE[1]	CLK_SEL	$Q_0 - Q_{21}$	$/Q_0 - /Q_{21}$
0	0	LOW	HIGH
0	1	LOW	HIGH
1	0	LVDS_CLK	/LVDS_CLK
1	1	LVPECL_CLK	/LVPECL_CLK

NOTE:

1. The OE (output enable) signal is synchronized with the low level of the LVDS_CLK and LVPECL_CLK signal.

SIGNAL GROUPS

Signal	I/O	Level
LVDS_CLK, /LVDS_CLK	Input	LVDS
$Q_0 - Q_{21}$, $/Q_0 - /Q_{21}$	Output	LVPECL
LVPECL_CLK, /LVPECL_CLK	Input	LVPECL
CLK_SEL, OE	Input	LVCMOS/LVTTL

ABSOLUTE MAXIMUM RATINGS[1]

Symbol	Rating		Value	Unit
V_{CCI}/ V_{CCO}	V_{CC} Pin Potential to Ground Pin		−0.5 to +4.0	V
V_{IN}	Input Voltage		−0.5 to V_{CCI}	V
I_{OUT}	DC Output Current		−50	mA
Tstore	Storage Temperature		−65 to +150	°C
θ_{JA}	Package Thermal Resistance (Junction-to-Ambient) With exposed pad soldered to GND	– Still-Air (multi-layer PCB) – 200lfpm (multi-layer PCB) – 500lfpm (multi-layer PCB)	23 18 15	°C/W °C/W °C/W
	Exposed pad _not_ soldered to GND	– Still-Air (multi-layer PCB) – 200lfpm (multi-layer PCB) – 500lfpm (multi-layer PCB)	44 36 30	°C/W °C/W °C/W
θ_{JC}	Package Thermal Resistance (Junction-to-Case)		4.3	°C/W

NOTE:

1. Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data book. Exposure to ABSOLUTE MAXIMUM RATING conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Power Supply

Symbol	Parameter	$T_A = -40°C$			$T_A = +25°C$			$T_A = +85°C$			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{CCI}, V_{CCO}	Power Supply[1]	2.37	—	3.6	2.37	—	3.8	2.37	—	3.6	V
I_{CC}	Total Supply Current[2]	—	100	150	—	100	150	—	100	150	mA

NOTES:

1. V_{CCI} and V_{CCO} must be connected together on the PCB such that they remain at the same potential. V_{CCI} and V_{CCO} are not internally connected on the die.
2. No load. Outputs floating.

LVDS Input (V_{CC} = 2.37V to 3.6V, GND = 0V)

Symbol	Parameter	$T_A = -40°C$			$T_A = +25°C$			$T_A = +85°C$			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{IN}	Input Voltage Range	0	—	2.4	0	—	2.4	0	—	2.4	V
V_{ID}	Differential Input Swing	100	—	—	100	—	—	100	—	—	mV
I_{IL}	Input Low Current[1]	−1.25	—	—	−1.25	—	—	−1.25	—	—	mA
R_{IN}	LVDS Differential Input Resistance (LVDS_CLK to /LVDS_CLK)	80	100	120	80	100	120	80	100	120	Ω

NOTE:

1. For I_{IL}, both LVDS inputs are grounded.

LVPECL Input/Output (V_{CC} = 2.37V to 3.6V, GND = 0V)

Symbol	Parameter	$T_A = -40°C$		$T_A = +25°C$		$T_A = +85°C$		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	Input HIGH Voltage (Single ended)	$V_{CC} - 1.165$	$V_{CC} - 0.88$	$V_{CC} - 1.165$	$V_{CC} - 0.88$	$V_{CC} - 1.165$	$V_{CC} - 0.88$	V
V_{IL}	Input LOW Voltage	$V_{CC} - 1.945$	$V_{CC} - 1.625$	$V_{CC} - 1.945$	$V_{CC} - 1.625$	$V_{CC} - 1.945$	$V_{CC} - 1.625$	V
V_{PP}	Minimum Input Swing[1] LVPECL_CLK	600	—	600	—	600	—	mV
V_{CMR}	Common Mode Range[2] LVPECL_CLK	−1.5	−0.4	−1.5	−0.4	−1.5	−0.4	V
V_{OH}	Output HIGH Voltage[3]	$V_{CCO} - 1.085$	$V_{CCO} - 0.880$	$V_{CCO} - 1.025$	$V_{CCO} - 0.880$	$V_{CCO} - 1.025$	$V_{CCO} - 0.880$	V
V_{OL}	Output LOW Voltage[3]	$V_{CCO} - 1.830$	$V_{CCO} - 1.555$	$V_{CCO} - 1.810$	$V_{CCO} - 1.620$	$V_{CCO} - 1.810$	$V_{CCO} - 1.620$	V
I_{IH}	Input HIGH Current	—	150	—	150	—	150	µA
I_{IL}	Input LOW Current	0.5	—	0.5	—	0.5	—	µA

NOTES:

1. The V_{PP} (min.) is defined as the minimum input differential voltage which will cause no increase in the propagation delay.

2. V_{CMR} is defined as the range within which the V_{IH} level may vary, with the device still meeting the propagation delay specification. The numbers in the table are referenced to V_{CCI}. The V_{IL} level must be such that the peak-to-peak voltage is less than 1.0V and greater than or equal to V_{PP} (min.). The lower end of the CMR range varies 1:1 with V_{CCI}. The V_{CMR} (min) will be fixed at 3.3V − |V_{CMR} (min)|.

3. Outputs loaded with 50Ω to V_{CC} -2V.

LVCMOS/LVTTL Control Inputs (OE, CLK_SEL) (V_{CC} = 2.37V to 3.6V, GND = 0V)

Symbol	Parameter	$T_A = -40°C$			$T_A = +25°C$			$T_A = +85°C$			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{IH}	Input HIGH Voltage	2.0	—	—	2.0	—	—	2.0	—	—	V
V_{IL}	Input LOW Voltage	—	—	0.8	—	—	0.8	—	—	0.8	V
I_{IH}	Input HIGH Current	+20	—	−250	+20	—	−250	+20	—	−250	µA
I_{IL}	Input LOW Current	—	—	−600	—	—	−600	—	—	−600	µA

AC ELECTRICAL CHARACTERISTICS[1]

V_{CC} = 2.37V to 3.6V, GND = 0V

Symbol	Parameter	T_A = −40°C			T_A = +25°C			T_A = +85°C			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
f_{MAX}	Max Toggle Frequency[2]	2	—	—	2	—	—	2	—	—	GHz
t_{PHL} t_{PLH}	Propagation Delay (Differential)[3] LVPECL IN LVDS IN	0.600 0.800	— —	1.2 1.4	0.600 0.800	0.900 1.1	1.2 1.4	0.600 0.800	— —	1.2 1.4	ns
t_{SKEW}	Within-Device Skew[4]	—	—	35	—	20	35	—	—	35	ps
	Part-to-Part Skew[5]	—	100	200	—	100	200	—	100	200	ps
$t_{S(OE)}$	OE Set-Up Time[6]	1.0	—	—	1.0	—	—	1.0	—	—	ns
$t_{H(OE)}$	OE Hold Time[6]	0.5	—	—	0.5	—	—	0.5	—	—	ns
t_r t_f	Output Rise/Fall Time (20% − 80%)	300	—	600	300	450	600	300	—	600	ps
$t_{(switchover)}$	Input Switchover CLK_SEL-to-valid output	—	—	1.2	—	—	1.2	—	—	1.2	ns

NOTES:

1. Outputs loaded with 50Ω to V_{CC} − 2V. Airflow ≥ 300lfpm.

2. f_{MAX} is defined as the maximum toggle frequency measured. Measured with a 750mV input signal, all loading with 50Ω to V_{CC} −2V.

3. Differential propagation delay is defined as the delay from the crossing point of the differential input signals to the crossing point of the differential output signals.

4. The within-device skew is defined as the worst case difference between any two similar delay paths within a single device operating at the same voltage and temperature.

5. The part-to-part skew is defined as the absolute worst case difference between any two delay paths on any two devices operating at the same voltage and temperature. Part-to-part skew is the total skew difference; pin-to-pin skew + part-to-part skew.

6. Set-up and hold time applies to synchronous applications that intend to enable/disable before the next clock cycle. For asynchronous applications, set-up and hold time does not apply. OE set-up time is defined with respect to the rising edge of the clock. OE HIGH to LOW transition ensures outputs remain disabled during the next clock cycle. OE LOW to HIGH transition enables normal operation of the next input clock.

PRODUCT ORDERING CODE

Ordering Code	Package Type	Operating Range	Package Marking
SY89825UHI	H64-1	Industrial	SY89825UHI

LVDS/LVPECL INPUTS

LVPECL Input Stage
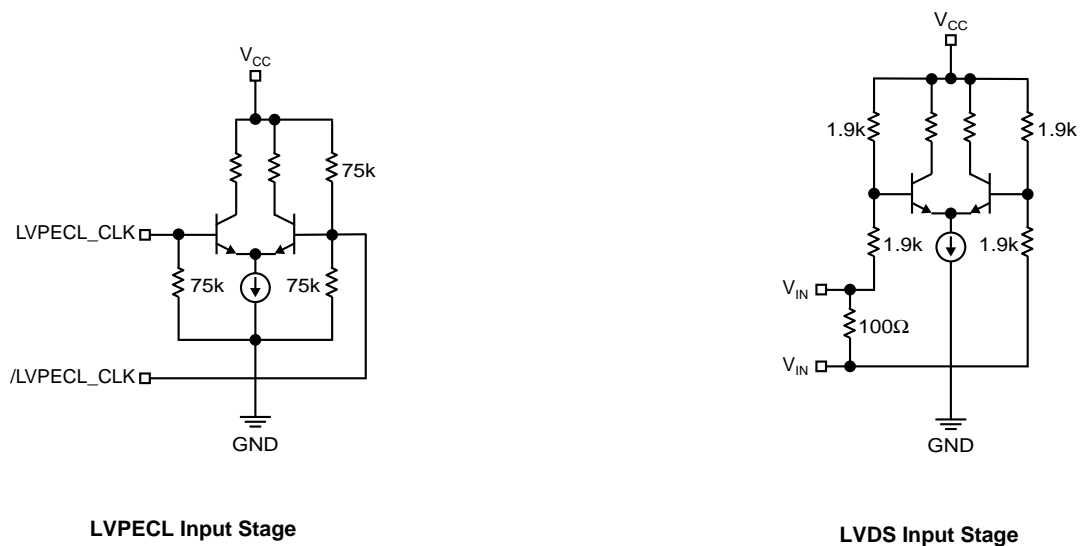
LVDS Input Stage

Figure 1. Simplified LVPECL & LVDS Input Stage

TYPICAL CHARACTERISTICS

**Frequency Response
vs. Output Amplitude**

V_{SUP} = 2.5V
V_{DIFFIN} = 800mV

OUTPUT AMPLITUDE (mV)
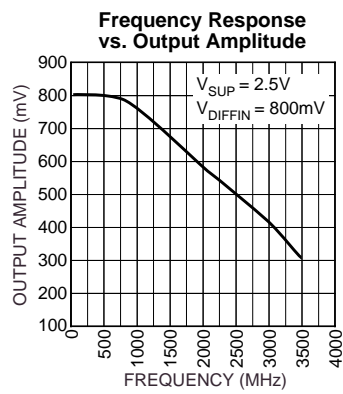
FREQUENCY (MHz)

**Frequency Response
vs. Output Amplitude @2.5V**

**Frequency Response
vs. Output Amplitude**

V_{SUP} = 3.3V
V_{DIFFIN} = 800mV

OUTPUT AMPLITUDE (mV)
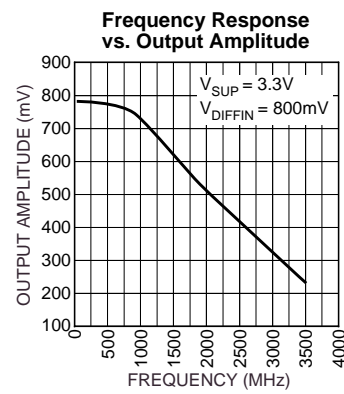
FREQUENCY (MHz)

**Frequency Response
vs. Output Amplitude @3.3V**

LVPECL TERMINATION RECOMMENDATIONS

Output Considerations

Be sure to properly terminate all outputs as shown below, or equivalent. For AC coupled applications, be sure to include a pull down resistor at the output of each driver. The emmiter follower outputs requires a DC current path to GND. Unused outputs can be left floating with minimal impact on skew and jitter.
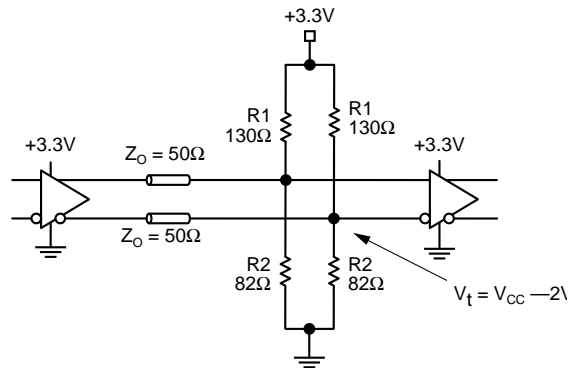

Figure 1. Parallel Termination–Thevenin Equivalent
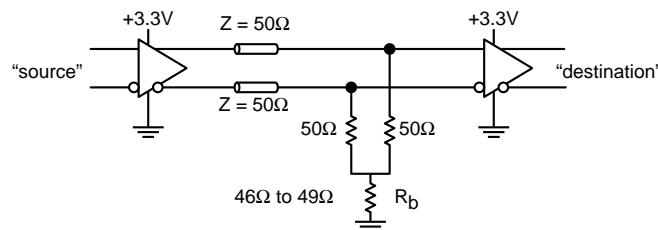
Notes:

1. For +2.5V systems:
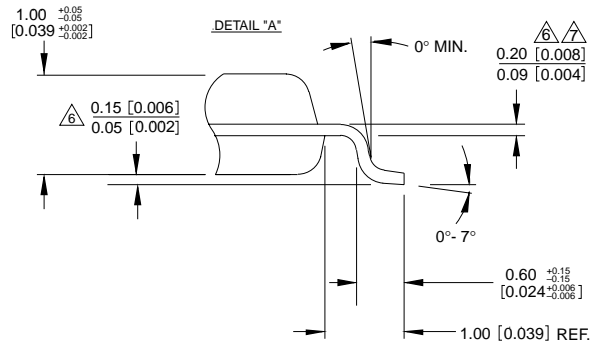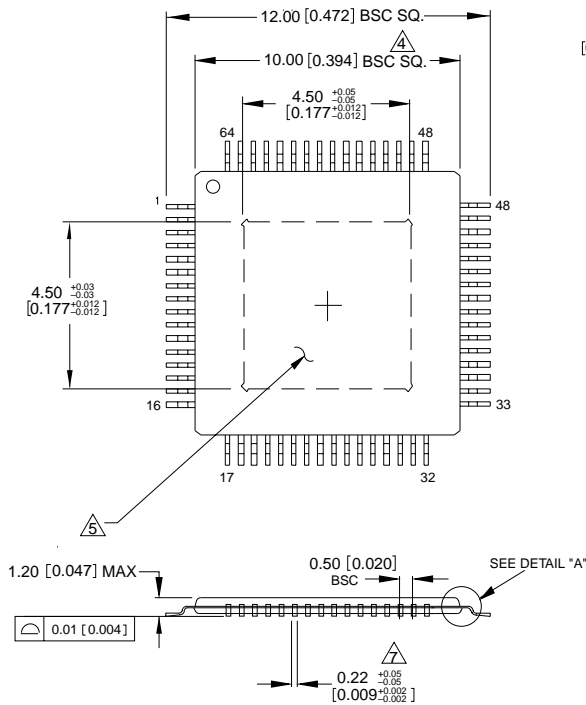
   R1 = 250Ω

   R2 = 62.5Ω

Figure 2. Three-Resistor "Y–Termination"

Notes:

1. Power-saving alternative to Thevenin termination.

2. Place termination resistors as close to destination inputs as possible.

3. R_b resistor sets the DC bias voltage equal to V_t. For +3.3V systems R_b = 46Ω to 49Ω.

4. Precision, low-cost 3-Resistor networks are available from resistor manufacturers such as Thin Film Technology (www.thinfilm.com).

64 LEAD EPAD-TQFP (DIE UP) (H64-1)

12.00 [0.472] BSC SQ.

10.00 [0.394] BSC SQ.

4.50 $^{+0.05}_{-0.05}$ [0.177$^{+0.012}_{-0.012}$]

4.50 $^{+0.03}_{-0.03}$ [0.177$^{+0.012}_{-0.012}$]

64 48

1

48

16 33

17 32

△5

1.20 [0.047] MAX

⬠ 0.01 [0.004]

0.50 [0.020]
BSC

SEE DETAIL "A"

△7

0.22 $^{+0.05}_{-0.05}$ [0.009$^{+0.002}_{-0.002}$]

1.00 $^{+0.05}_{-0.05}$ [0.039$^{+0.002}_{-0.002}$]

DETAIL "A"

0° MIN.

△6 △7
0.20 [0.008]
0.09 [0.004]

△6 0.15 [0.006]
0.05 [0.002]

0°- 7°

0.60 $^{+0.15}_{-0.15}$ [0.024$^{+0.006}_{-0.006}$]

1.00 [0.039] REF.

NOTES:
1. DIMENSIONS ARE IN MM[INCHES].
2. CONTROLLING DIMENSION: MM.
3. EXPOSED PAD: Cu WITH Sn/Pb PLATING.
△4 DIMENSION DOES NOT INCLUDE MOLD FLASH OF 0.254[0.010] MAX.
△5 DIE UP ORIENTATION SHOWN. EXPOSED PAD IS VISIBLE FROM BOTTOM OF PACKAGE.
△6 MAXIMUM AND MINIMUM SPECIFICATIONS ARE INDICATED AS FOLLOWS: MAX/MIN
△7 THIS DIMENSION INCLUDES LEAD FINISH.

Rev. 03